Nico Kaiser

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/5098066/publications.pdf

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11	191 citations	1307594 7 h-index	1372567 10 g-index
papers	Citations	II-IIIQEX	g-mdex
11 all docs	11 docs citations	11 times ranked	219 citing authors

#	Article	IF	CITATIONS
1	Formingâ€Free Grain Boundary Engineered Hafnium Oxide Resistive Random Access Memory Devices. Advanced Electronic Materials, 2019, 5, 1900484.	5.1	57
2	Defect-Stabilized Substoichiometric Polymorphs of Hafnium Oxide with Semiconducting Properties. ACS Applied Materials & Defect-Stabilized Substoichiometric Polymorphs of Hafnium Oxide with Semiconducting Properties.	8.0	27
3	Analysis and simulation of the multiple resistive switching modes occurring in $HfO×-based$ resistive random access memories using memdiodes. Journal of Applied Physics, 2019, 125, .	2.5	26
4	Enhanced thermal stability of yttrium oxide-based RRAM devices with inhomogeneous Schottky-barrier. Applied Physics Letters, 2020, 117, .	3.3	26
5	Tailoring the Switching Dynamics in Yttrium Oxideâ€Based RRAM Devices by Oxygen Engineering: From Digital to Multiâ€Level Quantization toward Analog Switching. Advanced Electronic Materials, 2020, 6, 2000439 Role of Oxygen Defects in Conductive-Filament Formation in <mml:math< td=""><td>5.1</td><td>20</td></mml:math<>	5.1	20
6	xmlns:mmi="http://www.w3.org/1998/Math/MathML" display="inline" overflow="scroll"> <mml:msub><mml:mi mathvariant="normal">Y<mml:mn>2</mml:mn></mml:mi </mml:msub> <mml:msub><mml:mi mathvariant="normal">O<mml:mn>3</mml:mn></mml:mi </mml:msub> -Based Analog	3.8	15
7	RRAM Devices as Revealed by Fluctuation Spectroscopy. Physical Review Applied, 2020, 14, . Defect-Induced Phase Transition in Hafnium Oxide Thin Films: Comparing Heavy Ion Irradiation and Oxygen-Engineering Effects. IEEE Transactions on Nuclear Science, 2021, 68, 1542-1547.	2.0	12
8	Machine Learning Assisted Pattern Matching: Insight into Oxide Electronic Device Performance by Phase Determination in 4D-STEM Datasets. Microscopy and Microanalysis, 2020, 26, 1908-1909.	0.4	3
9	Heavy Ion Irradiation Effects on Structural and Ferroelectric Properties of HfO ₂ Films., 2020,,.		3
10	Correlation of Structural Modifications by Multiscale Phase Mapping in Filamentary Type HfO2-based RRAM: Towards a Component Specific in situ TEM Investigation. Microscopy and Microanalysis, 2019, 25, 1842-1843.	0.4	1
11	Enhanced Conductivity and Microstructure in Highly Textured TiN _{1â€"<i>x</i>} / <i></i> <td>3.5</td> <td>1</td>	3.5	1